

INK0001AC1-T150

High speed switching
Silicon N-channel MOSFET

AEC-Q101 Compliance

DESCRIPTION

INK0001AC1 is a Silicon N-channel MOSFET.

This product is most suitable for low voltage use such as portable machinery, because of low voltage drive and low resistance.

FEATURE

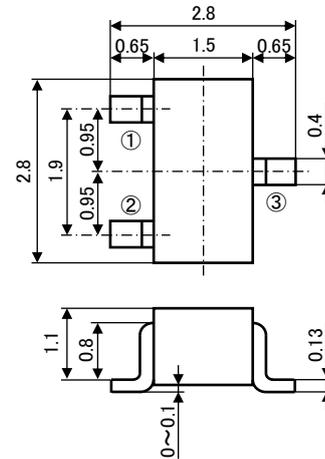
- Input impedance is high, and not necessary to consider a drive electric current.
- Drive voltage 2.5V
- Low on Resistance.
 $R_{DS(ON)}=3.5\ \Omega$ (TYP) @ $I_D=100\text{mA}$, $V_{GS}=4.0\text{V}$
- High speed switching.
- Small packing for easy mounting.

APPLICATION

Inductive loads switching

OUTLINE DRAWING

Unit: mm



TERMINAL CONNECTOR

JEITA— : SC-59

JEDEC: Similar to TO-236

①: GATE

②: SOURCE

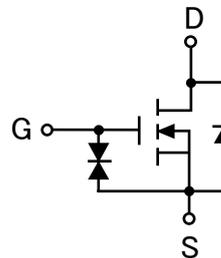
③: DRAIN

MAXIMUM RATINGS ($T_a=25^\circ\text{C}$)

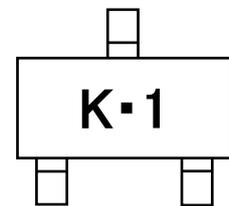
Parameter	Symbol	Rating	Unit
Drain-Source voltage	V_{DSS}	50	V
Gate-Source voltage	V_{GSS}	± 8	V
Drain current(DC)	I_D	100	mA
Drain current(Pulse)	I_{DP}	400(※1)	mA
Total power dissipation	P_D	200	mW
Channel temperature	T_{ch}	+150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55~+150	$^\circ\text{C}$

※1: $P_w \leq 10\ \mu\text{s}$, Duty cycle $\leq 1\%$

EQUIVALENT CIRCUIT



MARKING



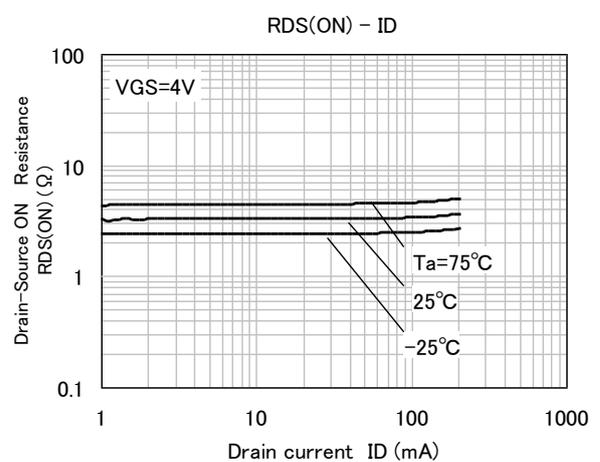
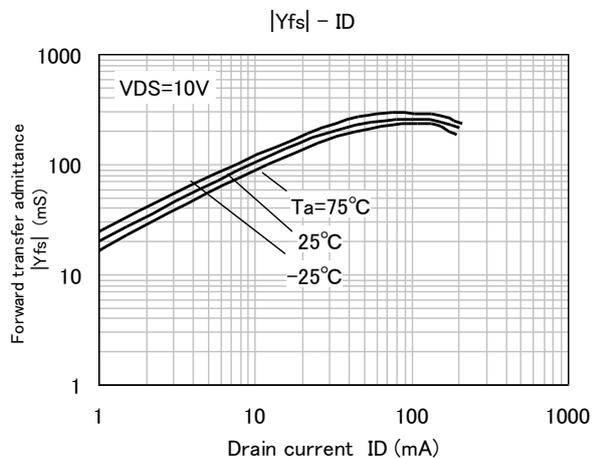
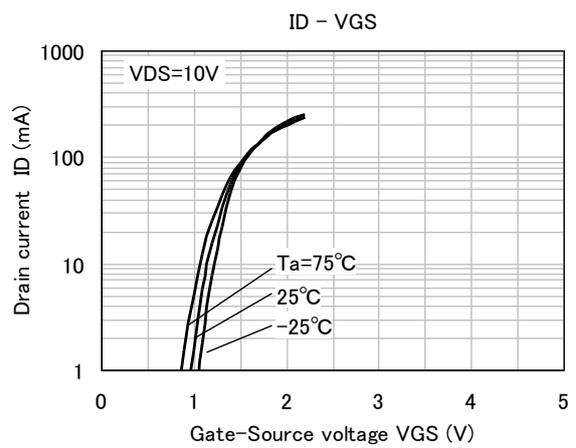
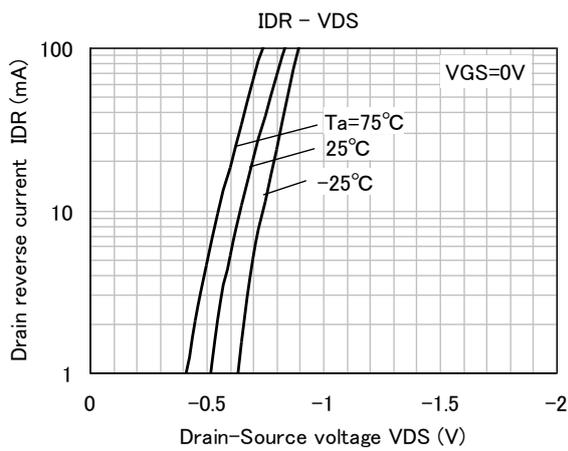
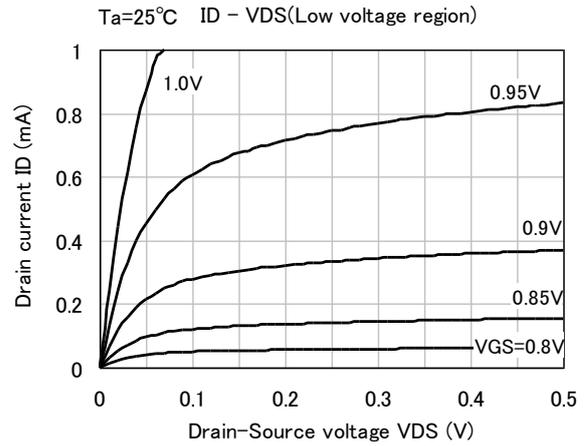
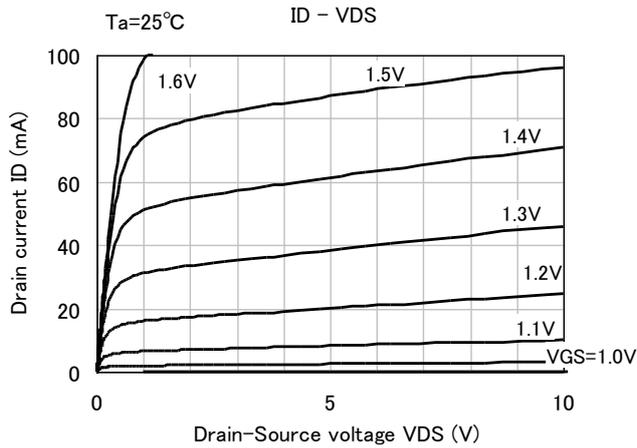
ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$)

Parameter	Symbol	Test Condition	Limit			Unit
			MIN	TYP	MAX	
Drain-Source breakdown voltage	$V_{(BR)DSS}$	$I_D=100\ \mu\text{A}$, $V_{GS}=0\text{V}$	50	-	-	V
Gate-Source leak current	I_{GSS}	$V_{GS}=\pm 5\text{V}$, $V_{DS}=0\text{V}$	-	-	± 0.5	μA
Zero gate voltage drain current	I_{DSS}	$V_{DS}=50\text{V}$, $V_{GS}=0\text{V}$	-	-	1.0	μA
Gate threshold voltage	V_{th}	$I_D=250\ \mu\text{A}$, $V_{DS}=V_{GS}$	0.6	-	1.2	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS}=10\text{V}$, $I_D=0.1\text{A}$	-	250	-	mS
Static Drain-Source on-state resistance	$R_{DS(ON)}$	$I_D=100\text{mA}$, $V_{GS}=4.0\text{V}$	-	3.5	-	Ω
Input capacitance	C_{iss}	$V_{DS}=10\text{V}$, $V_{GS}=0\text{V}$, $f=1\text{MHz}$	-	24	-	pF
Output capacitance	C_{oss}		-	5	-	
Switching time	t_{on}	$V_{DD}=5\text{V}$, $I_D=10\text{mA}$	-	11	-	ns
	t_{off}	$V_{GS}=0\sim 5\text{V}$	-	50	-	

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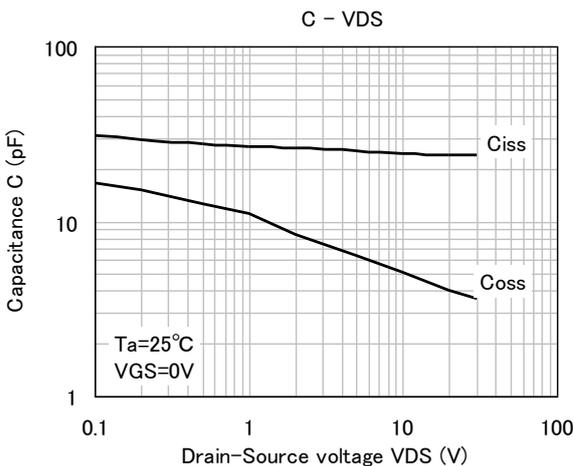
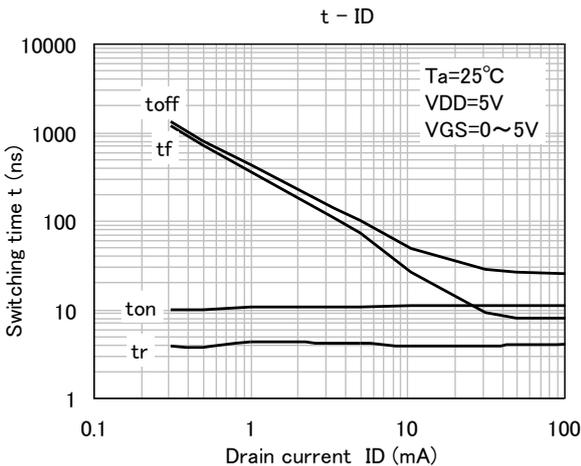
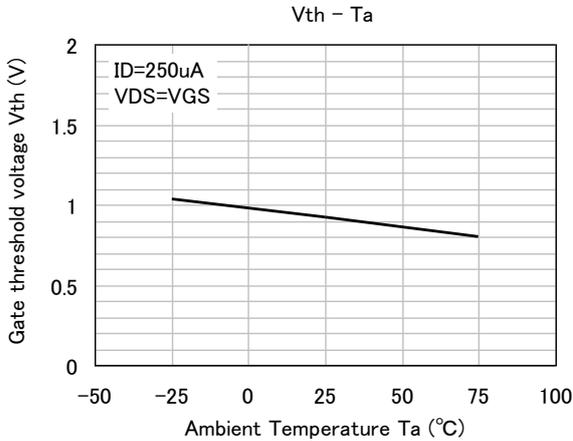
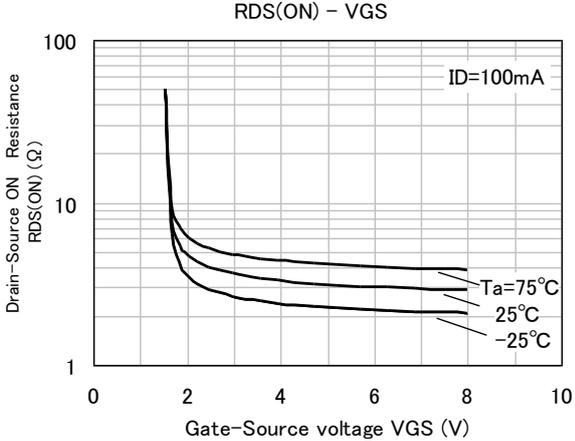
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TYPICAL CHARACTERISTICS

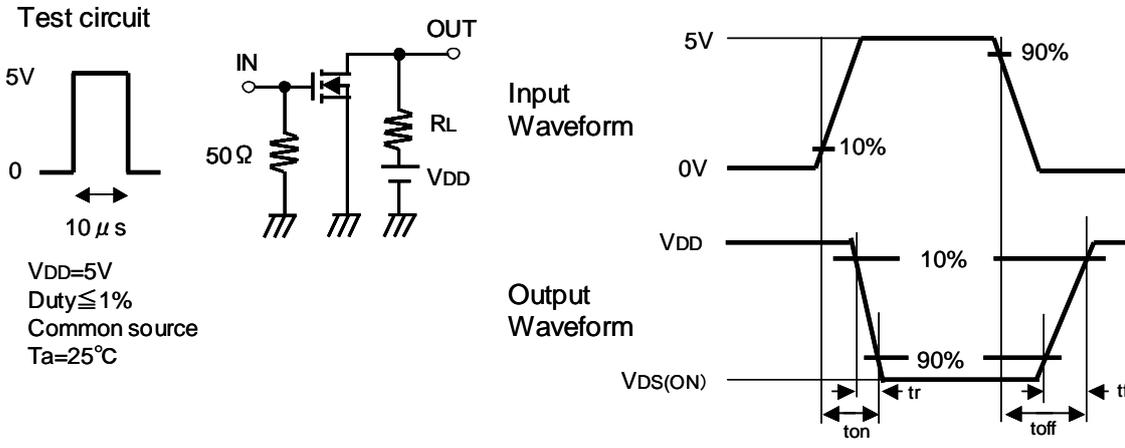


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Switching time test condition



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